

FEATURES

- Low Reverse Recovery Charge
- High Switching Speed
- Low Forward Volt Drop
- Isolated AISiC Base with AlN Substrates
- Dual Diodes can be paralleled for 1500A Rating
- Lead Free Construction
- 10.2kV Isolation Package

APPLICATIONS

- Brake Chopper Diodes
- Boost and Buck Circuits
- Free-wheel Circuits
- Motor Drives
- Resonant Converters
- Induction Heating
- Multi-level Switch Inverters

The DFM750XXM65-TS000 is a dual 6500V, fast recovery diode (FRD) module. Designed for low power loss, the module is suitable for a variety of high voltage applications in motor drives and power conversion.

Fast switching times and low reverse recovery losses allow high frequency operation, making the device suitable for the latest drive designs employing PWM and high frequency switching.

The module incorporates an electrically isolated base plate and low inductance construction enabling circuit designers to optimise circuit layouts and utilise grounded heat sinks for safety.

ORDERING INFORMATION

Order As:

DFM750XXM65-TS000

Note: When ordering, please use the complete part number

KEY PARAMETERS

V_{RRM}		6500V
V_F	(typ)	3.3V
I_F	(max)	750A
I_{FM}	(max)	1500A

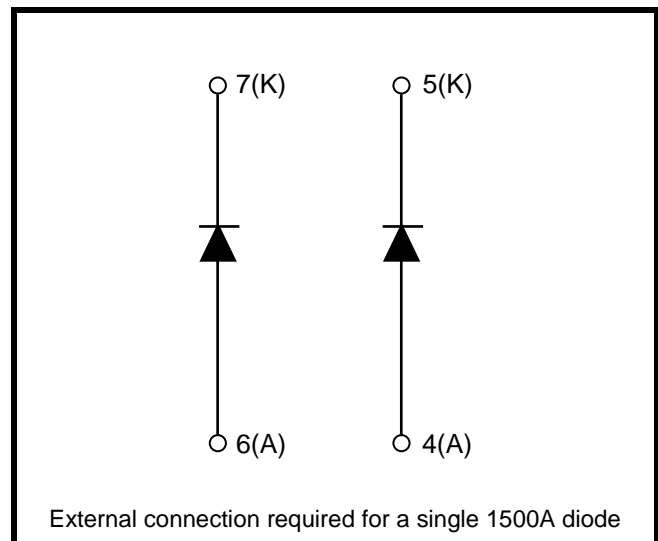


Fig. 1 Circuit configuration

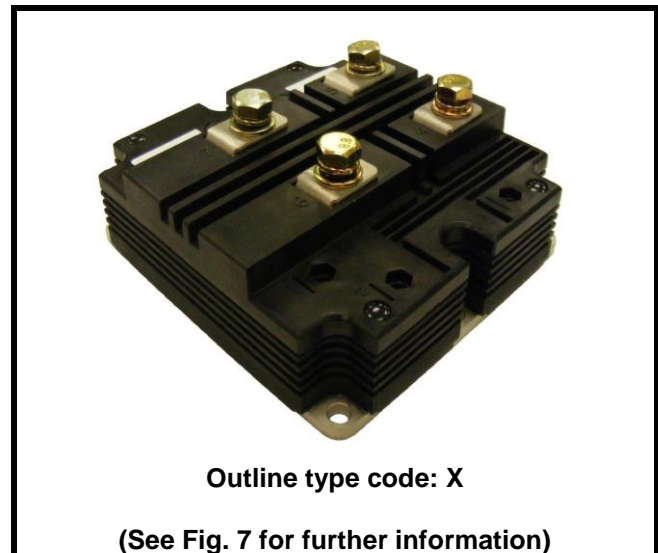


Fig. 2 Package

STATIC ELECTRICAL CHARACTERISTICS – PER ARM

$T_{case} = 25^{\circ}\text{C}$ unless stated otherwise.

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
I_{RM}	Peak reverse current	$V_R = 6500\text{V}, T_j = 125^{\circ}\text{C}$			50	mA
V_F	Forward voltage	$I_F = 750\text{A}$		3.3		V
		$I_F = 750\text{A}, T_j = 125^{\circ}\text{C}$		3.7		V
L_M	Inductance	-		40		nH

STATIC ELECTRICAL CHARACTERISTICS

$T_{case} = 25^{\circ}\text{C}$ unless stated otherwise.

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
L_M	Module inductance (externally connected in parallel)	-		20		nH
R_{INT}	Internal resistance (per arm)	-		370		$\mu\Omega$

DYNAMIC ELECTRICAL CHARACTERISTICS – PER ARM

$T_{case} = 25^{\circ}\text{C}$ unless stated otherwise

Symbol	Parameter	Test Conditions	Min	Typ.	Max	Units
Q_{rr}	Reverse recovery charge	$I_F = 750\text{A}$ $V_R = 3600\text{V}$ $di_F/dt = 4000\text{A}/\mu\text{s}$		1500		μC
I_{rr}	Peak reverse recovery current			1550		A
E_{rec}	Reverse recovery energy			2700		mJ

$T_{case} = 125^{\circ}\text{C}$ unless stated otherwise

Symbol	Parameter	Test Conditions	Min	Typ.	Max	Units
Q_{rr}	Reverse recovery charge	$I_F = 750\text{A}$ $V_R = 3600\text{V}$ $di_F/dt = 4200\text{A}/\mu\text{s}$		2500		μC
I_{rr}	Peak reverse recovery current			2350		A
E_{rec}	Reverse recovery energy			4300		mJ

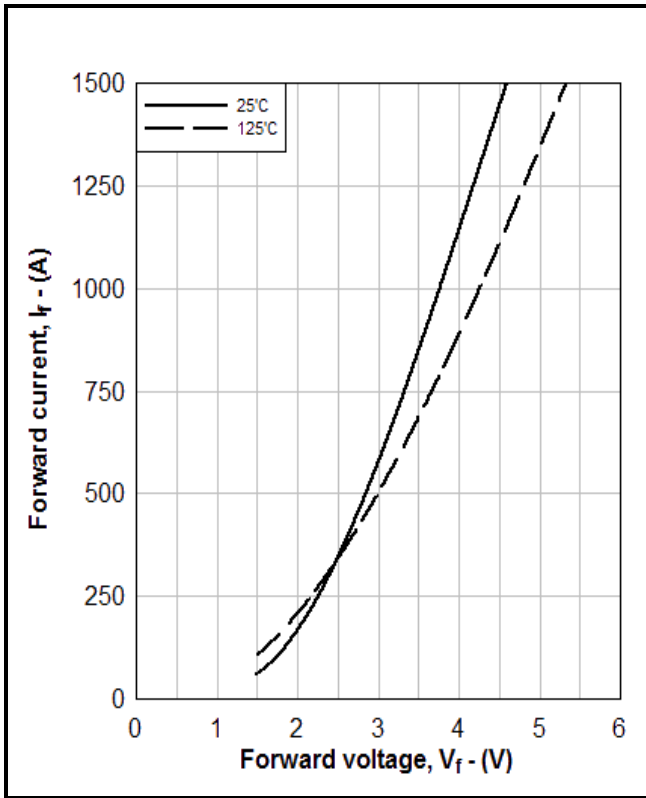


Fig. 3 Diode typical forward characteristics

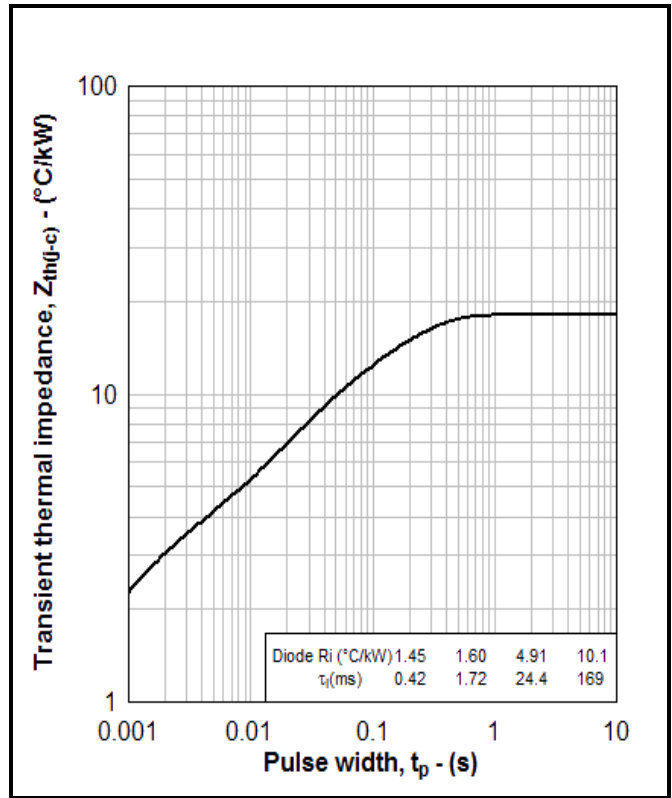


Fig. 4 Transient thermal impedance

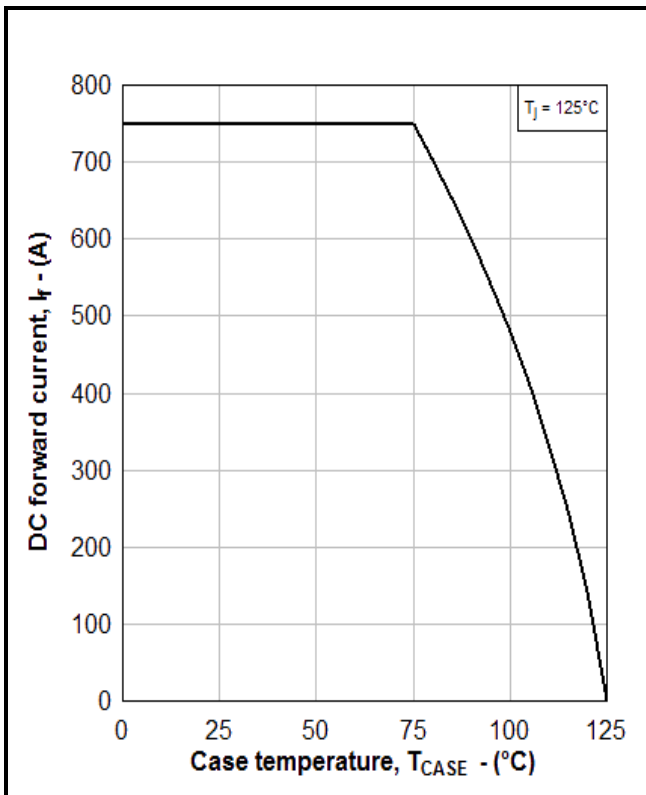


Fig. 5 DC current rating vs case temperature

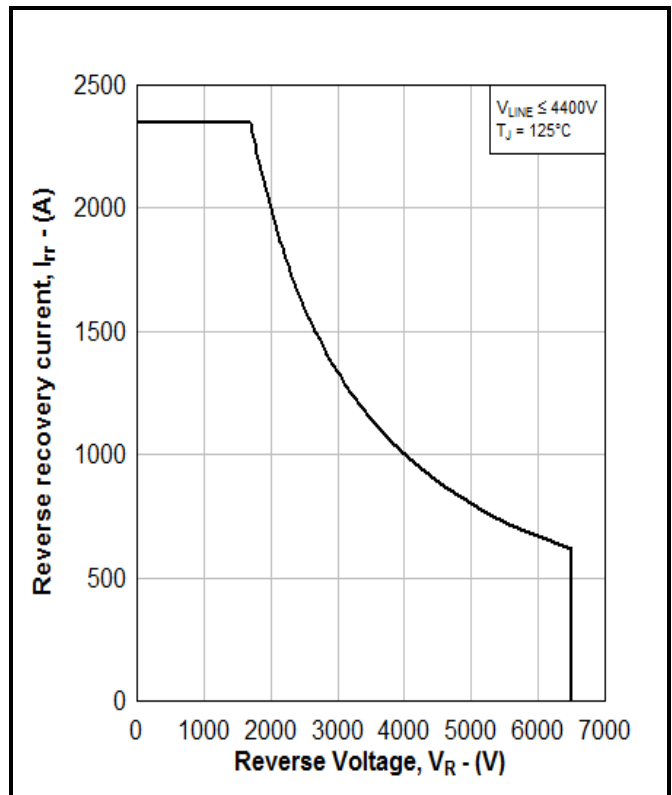


Fig. 6 Reverse Bias Safe Operating Area (RBSOA)

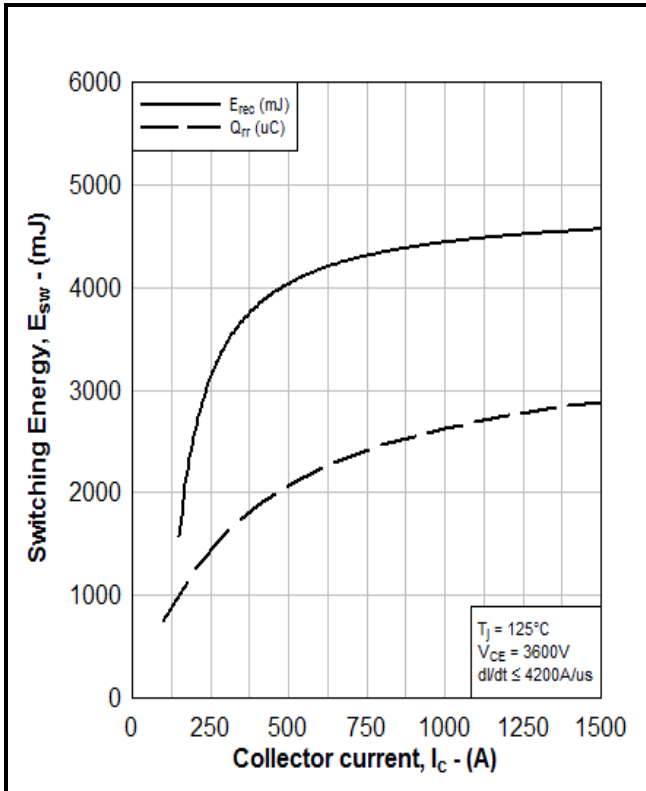


Fig. 7 Characteristics vs. current

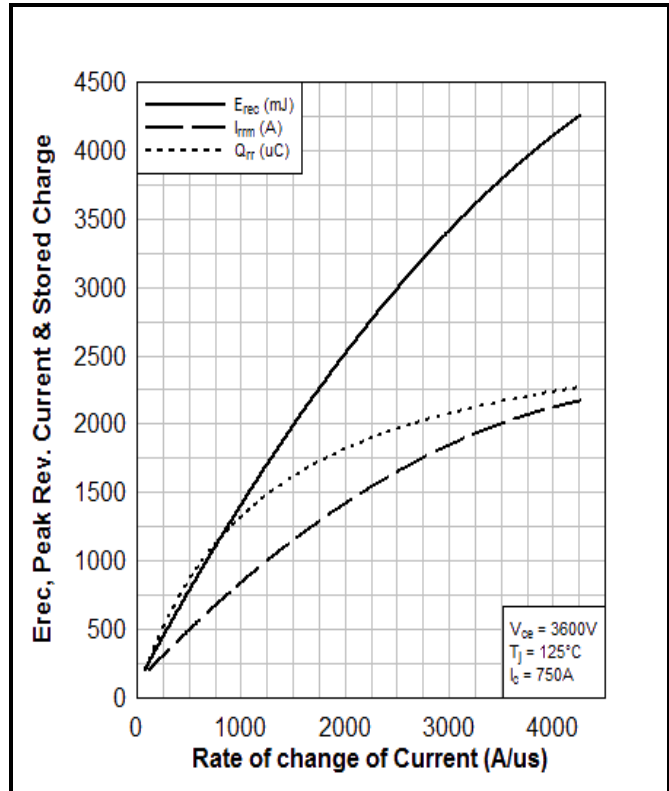
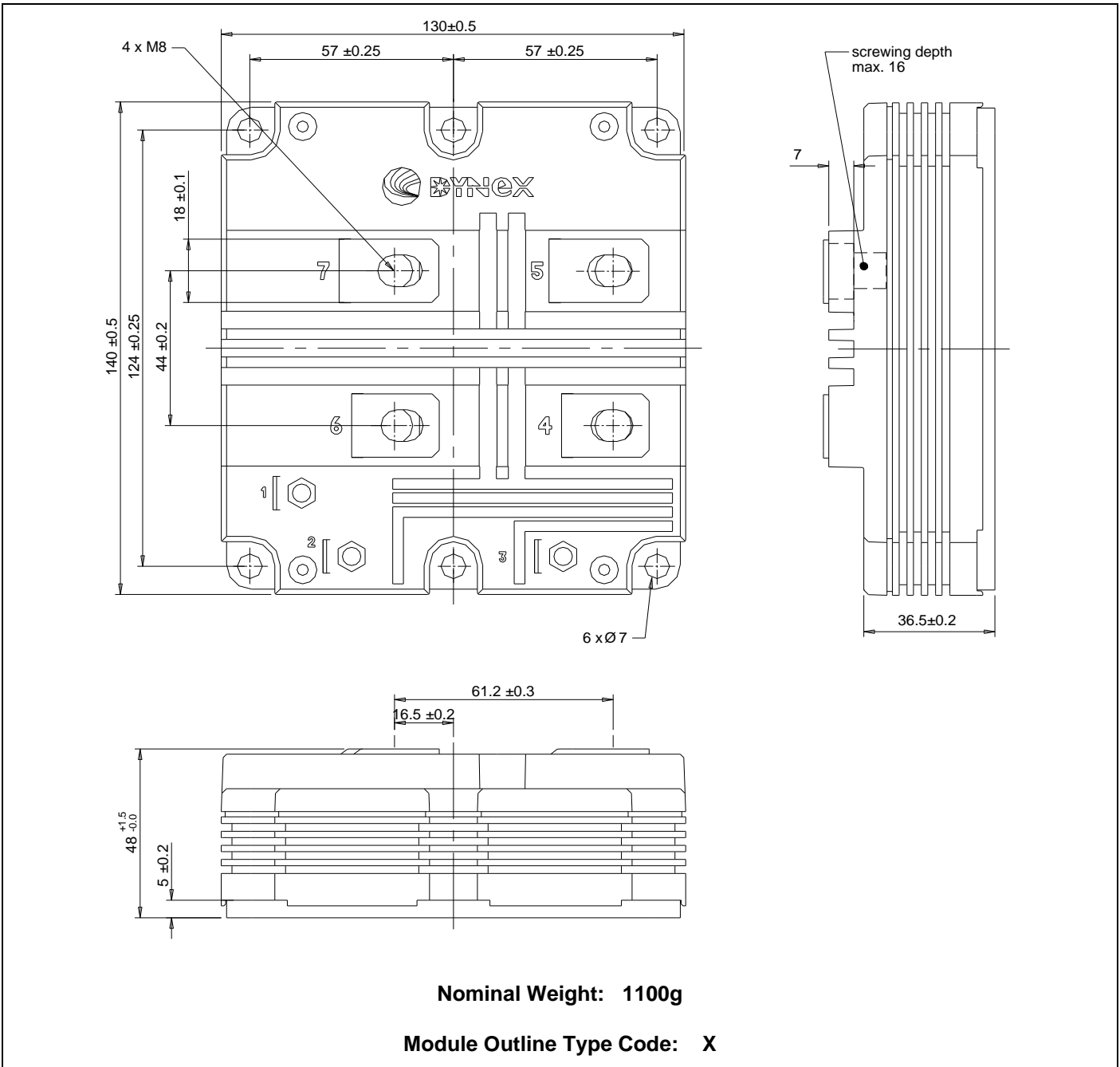


Fig. 8 Characteristic vs. di/dt

PACKAGE DETAILS

For further package information, please visit our website or contact Customer Services.
All dimensions in mm, unless stated otherwise.
DO NOT SCALE.



Nominal Weight: 1100g

Module Outline Type Code: X

Fig. 9 Module outline drawing

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Preliminary Information:	The product design is complete and final characterisation for volume production is in progress. The datasheet represents the product as it is now understood but details may change.
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